ON Semiconductor

Is Now

Onsemi

To learn more about onsemi[™], please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari

Schottky Barrier Rectifier, Trench-based, High Performance

NRTS6100TFS

This Trench Schottky rectifier is high performance device in μ 8–FL package. The lower forward voltage, less leakage current, and small junction capacitance are suitable to high switching frequency high density DC to DC conversion application. Offering higher avalanche energy capability for Oring or reverse protection application. The μ 8–FL package provides an excellent thermal performance, less land area of board space, and low profile.

Features

- Lower Forward Voltage Drop
- Less Leakage Current in High Temperature
- Small Junction Capacitance for High Switching Frequency
- Higher Avalanche Energy Capability
- 175°C Operating Junction Temperature
- Good Alternative Solution of SMA and SMB Package
- Small Footprint Land Area: 12.5 mm²
- Low Profile Maximum Height of 1.1 mm
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 95 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds
- MSL 1

Applications

- High Switching Frequency DC/DC Converter
- 2nd Rectifier
- Freewheeling Diode used with Inductive Load
- Oring / Reverse Protection



ON Semiconductor®

www.onsemi.com

TRENCH SCHOTTKY RECTIFIER 6.0 AMPERE 100 VOLTS



(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NRTS6100TFSTAG	WDFN8 (Pb-Free)	1500/Tape & Reel Pin1 Upper Left
NRTS6100TFSTWG	WDFN8 (Pb-Free)	5000/Tape & Reel Pin1 Upper Left
NRTS6100TFSTBG	WDFN8 (Pb-Free)	1500/Tape & Reel Pin1 Upper Right
NRTS6100TFSTXG	WDFN8 (Pb-Free)	5000/Tape & Reel Pin1 Upper Right

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

Ra	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V	
Continuous Forward Current ($T_C = 167^{\circ}C$	I _{F(DC)}	6	А	
Peak Repetitive Forward Current ($T_C = 10$	I _{FRM}	12	А	
Non-Repetitive Peak Surge Current	petitive Peak Surge Current Sinusoidal Halfwave, 8.3 ms I _{FSM}		150	А
	Square wave, 1 ms		300	1
	Square wave, 100 μs		500	1
Non-Repetitive Avalanche Energy ($T_J = 25^{\circ}C$)		E _{AS}	100	mJ
Storage Temperature Range		T _{stg}	-65 to +175	°C
Operating Junction Temperature Range (Note 1)		TJ	-55 to +175	°C
ESD Rating (Human Body Model)			3B	
ESD Rating (Machine Model)		M4		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient dP_D/dT_J < $1/R_{\theta JA}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	70	°C/W
Thermal Resistance, Junction-to-Case Bottom (Note 2)	$R_{\theta JCB}$	2.4	°C/W
Thermal Characterization, Junction-to-Case Top (Note 2)	ψјст	4.3	°C/W
Thermal Characterization, Junction-to-Lead of Cathode (Note 2)	ΨJLC	2.5	°C/W

2. Assume 600 mm², 1 oz. copper bond pad on a FR4 board.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
Instantaneous Forward Voltage	V _F			V
(I _F = 3 A, T _J = 25°C)		0.52	-	
(I _F = 3 A, T _J = 125°C)		0.47	-	
$(I_{F} = 6 \text{ A}, T_{J} = 25^{\circ}\text{C})$		0.62	0.68	
(I _F = 6 A, T _J = 125°C)		0.56	0.62	
Instantaneous Reverse Current	I _R			
(V _R = Rated DC Voltage, T _J = 25°C)		5.2	50	μA
(V _R = Rated DC Voltage, T_J = 125°C)		3.2	15	mA
Junction Capacitance	CJ			pF
(V _R = 1 V, T _J = 25°C, f = 1 MHz)		782	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width = $300 \ \mu$ s, Duty Cycle $\le 2.0\%$.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



Figure 9. Typical Thermal Characteristics, Junction-to-Ambient

PACKAGE DIMENSIONS

WDFN8 3.3x3.3, 0.65P CASE 511AB

ISSUE D

A

C

SEATING







з

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 1. 2
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.70	0.75	0.80	0.028	0.030	0.031	
A1	0.00		0.05	0.000		0.002	
b	0.23	0.30	0.40	0.009	0.012	0.016	
С	0.15	0.20	0.25	0.006	0.008	0.010	
D	3.30 BSC			0.130 BSC			
D1	2.95	3.05	3.15	0.116	0.120	0.124	
D2	1.98	2.11	2.24	0.078	0.083	0.088	
Е	3.30 BSC			0.130 BSC			
E1	2.95	3.05	3.15	0.116	0.120	0.124	
E2	1.47	1.60	1.73	0.058	0.063	0.068	
E3	0.23	0.30	0.40	0.009	0.012	0.016	
e	0.65 BSC			0.026 BSC			
G	0.30	0.41	0.51	0.012	0.016	0.020	
к	0.65	0.80	0.95	0.026	0.032	0.037	
L	0.30	0.43	0.56	0.012	0.017	0.022	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
М	1.40	1.50	1.60	0.055	0.059	0.063	
θ	0 °		12 °	0 °		12 °	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and water trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

